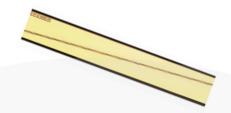


## Part Number: CHP-290 /CHP-290O

High Power SOA Chip Single-Mode SOA Wavelength at 1280nm & 1310 O-band



## **Features**

- High Output Power
- High Dynamic Range
- High Efficiency
- Standard SOA Bare Die
- Cost Effective

# **Application**

- OTDR
- LiDAR
- Free Space Communications
- Network Test Equipment

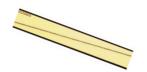


SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary, we will further optimize the design of our InP & GaSb laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.

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# Specification CHP-290 / CHP-2900



Optical	Symbol	Тур.	Тур.	Units
		CHP-290	CHP-290O	
Center Wavelength	λς	1280	1310	nm
Output Power @1A*	Pout	0.45	0.45	watts (±10%)
Aperture Width	AW	4	4	μm
Gain @ Pin = 10μW	G	35	35	dB
Gain Bandwidth	BW	80	80	nm
Beam Exit Angle	$\theta_{EXT}$	19.5	19.5	Degree
Noise Figure	NF	6	6	dB
Polarization Extinction Ratio	PER	18	18	dB
Fast Axis Div.	Θ⊥	28	28	Deg FWHM
Slow Axis Div.	Θ	16	16	Deg FWHM
Front Facet Reflectivity		<0.1%	<0.1%	
Rear Face Reflectivity		<0.1%	<0.1%	
Waveguide		Tilted Straight	Tilted Straight	
Electrical	Symbol			Units
Operating Current	lop	1	1	А
Operating Voltage	V <sub>op</sub>	2	2	V
Mechanical		Range	Range	Units
Chip Length		2500	2500	μm
Chip Width		500	500	μm
Operating Temp.**		-20 to 75	-20 to 75	°C
Storage Temp.		-40 to 85	-40 to 85	°C

\*Optical Power for 1310nm COC-288 and COC-290 with SOA drive current @ 1A and estimated Pin @ 7mW \*Optical Power for 1550nm COC-285 and COC-287 with SOA drive current @ 1A and estimated Pin @ 21mW \* Optical output power depends on the seed laser power, coupling efficiency, and thermal management.

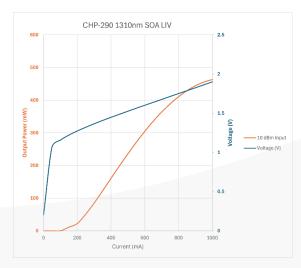
> \*Specified values are rated at a constant heat sink temperature of 20°C. \*\*High temperature operation will reduce performance and MTTF. Unless otherwise indicated all values are nominal.



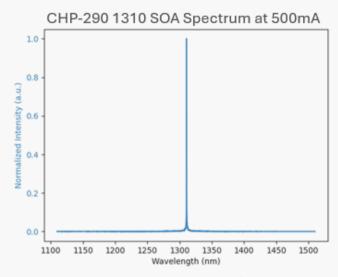
### SemiNex SOA CHP-290 & CHP-290O

## Graphs & Data

## Typical CHP L-I-V Characteristics



## Typical CHP Output Spectrum



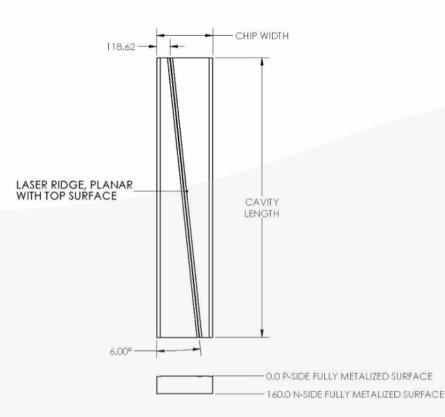
\*Graphs and Data were collected from mounted parts

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## **Mechanical Drawing**





CHIP ATTRIBUTES				
WAVELENGTH	1310n <b>m</b> ±20n <b>m</b>			
APERTURE WIDTH	4μm ±1μm			
CHIP WIDTH	0.500mm ±10µm			
THICKNESS	160µm±10µm			
CAVITY LENGTH	2.5mm +10um			

P-METAL				
MATERIAL	THICKNESS (nm)	TOLERANCE (nm)		
Ti	50	±10		
Pt	125	±25		
Au	250	±50		

N-METAL				
MATERIAL	THICKNESS (nm)	TOLERANCE (nm)		
Ti	30	±10		
Pt	125	±25		
Αu	400	±40		

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